Reg. No.:	
Name ·	



TERM END EXAMINATIONS (TEE) – December 2021- January 2022					
Programme	B-Tech (BAC, BAI, BAS, BCG, BHI, BMR, BOE, BSA)	Semester	: Fall 2021-22		
Course Name	: Electric Circuits and Systems	Code	: EEE1001		
Faculty Name	: Dr. Abhay Vidyarthi	Slot/ Class No.	: E11+E12+E13/0053		
Time	: 1 ½ hours	Max. Marks	: 50		

Answer ALL the Questions

Q. No.		Question Description	Marks		
	PART - A (30 Marks)				
1	(a)	Obtain the Thevenin equivalent network for the circuit shown in Fig.1	10		
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		Fig.1			
	OR				
	(b)	Find the equivalent inductance of the network shown in Fig. 2	10		
		$k_3 = 0.65$			
		k = 0.33 k = 0.37			
		$k_1 = 0.33$ $k_2 = 0.37$ 12 H 14 H 000 000			
		Fig. 2			
2	(a)	Explain the working of a single phase transformer with the help of a neat sketch.	10		
		OR			
	(b)	With the help of a neat sketch, explain the working of any two: I. BJT and its $V - I$ Characteristics	10		
		II. PN Diode and its $V - I$ Characteristics			
		III. Full wave Rectifiers			
		IV. Modes of operation of SCR			
		V. Depletion-type MOSFET			
3	(a)	Write the truth table of Full Subtractor and Half adders and how to design a Full Subtractor using two Half Adders and an <i>OR</i> gate.	10		

	OR					
	(b) Explain the working of 3-bit ripple down-counter with the help of <i>T</i> flip-flop	10				
	PART - B (20 Marks)					
4	Find the value of resistance RL as shown in Fig. 3 so as to deliver the maximum power transfer and also calculate the maximum power.	10				
5	Fig.3 Explain the significance of threshold voltage in case of N Channel Enhancement MOSFET. What happens to the current which is flowing from drain to the source if the drain to source voltage crosses the saturation voltage level? Explain the working of N Channel Enhancement MOSFET with the help of a neat sketch.					
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